Metasurface-assisted optical transparency of a continuous metal film

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15s-Summary.

Question: Transparent conductors are useful, but conventional ITO film is expensive and not sustainable.

Task: Find a new design strategy of transparent conductors based on continuous metal film.

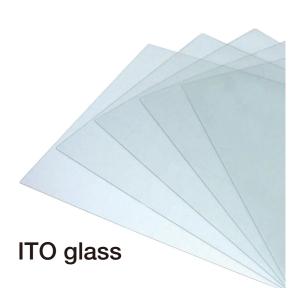
Results: A transparent metasurface/metal film/metasurface configuration is proposed based on Coupled Mode Theory (CMT).

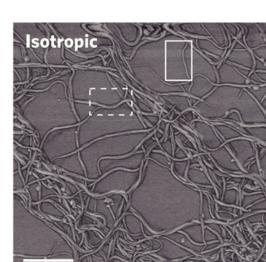
Free-standing samples were fabricated by the transmitted e-beam lithography technique. $T_{\text{max}} \approx 55\%$ is obtained for a 28nm thick Ag film.

Introduction

Former realizations of transparent conductors

- •Indium Tin Oxide (ITO): widely used, but expensive due to the scarcity of *indium*.
- Nanosturctures (cabon nanotube, Ag nanowire/mesh etc.) : low conductivity and high optical haze.
- Continuous metal film: good conductance, but hard to be made transparent.



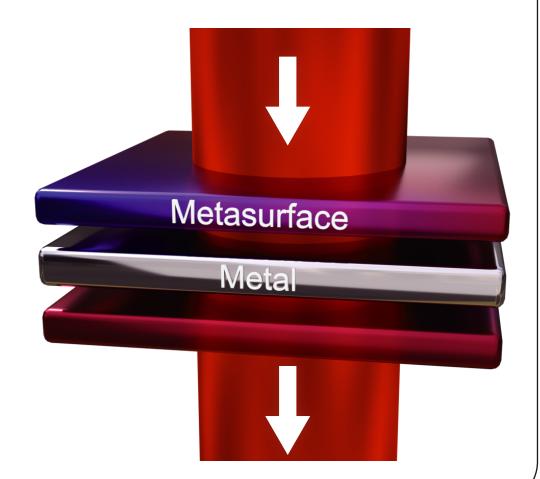


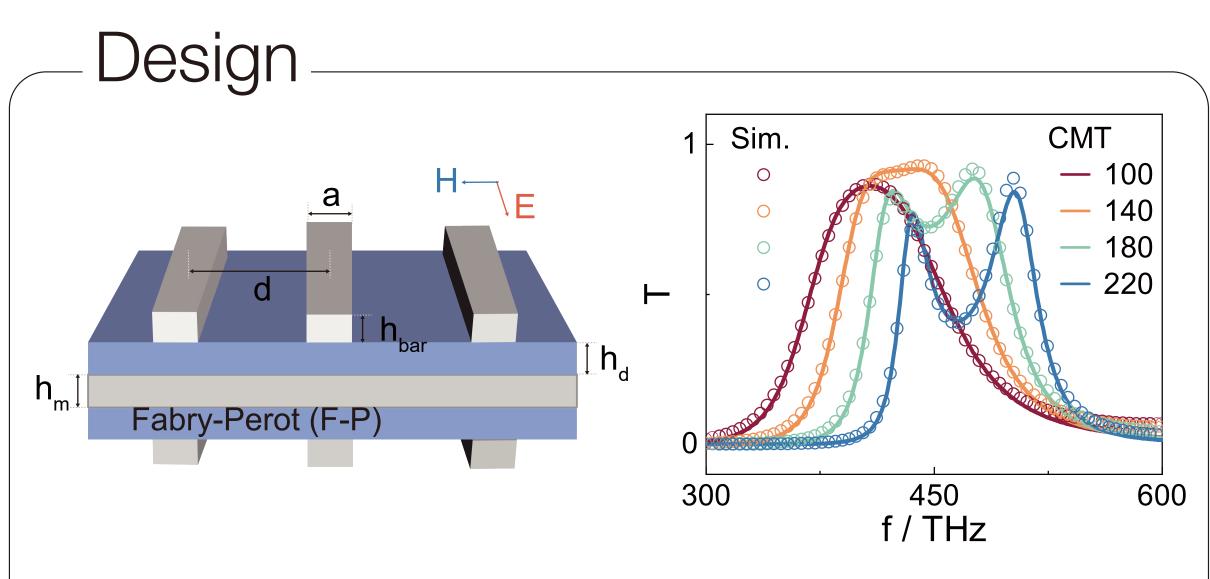
Al₂O₃ Cu-doped Ag ZnO PET Nat Commun (2020)

Nat Nanotech (2011)

Our results

- Metasurface-assisted transparency of a continuous metal film with numerical and experimental verifications.
- Transparency is interpreted by CMT.
- Optoelectronic performance comparable to ITO.

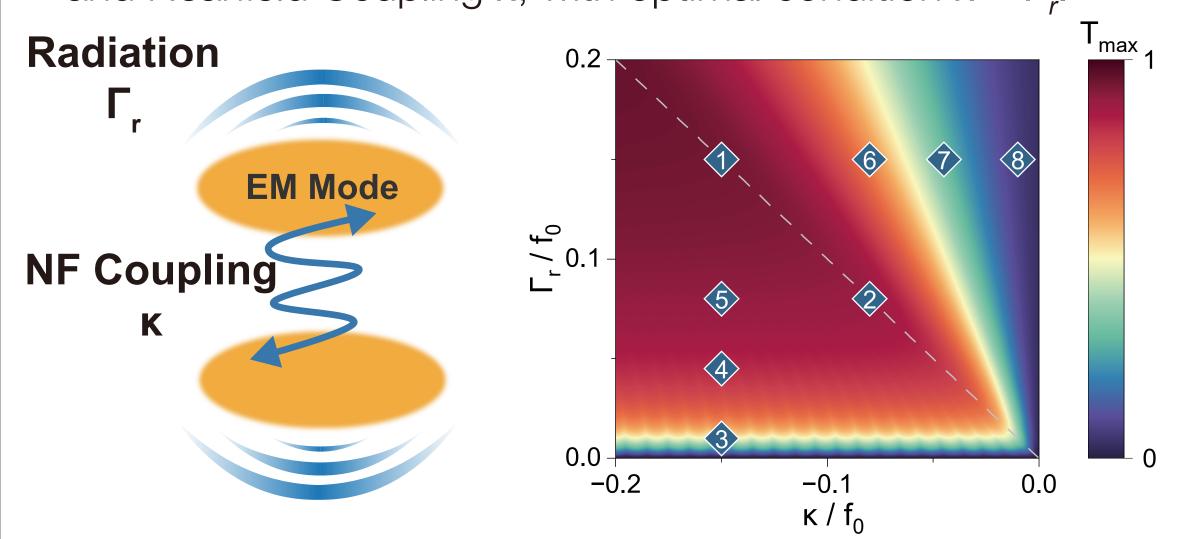




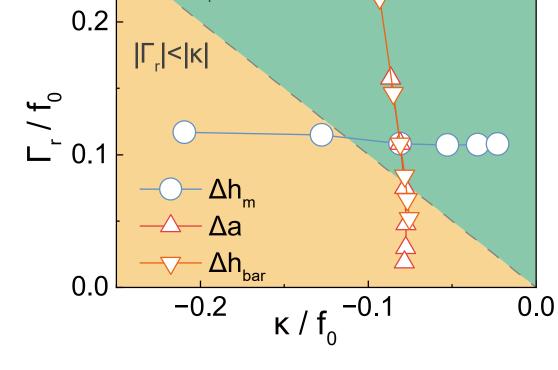
- •5-layer demo: Ag grating/SiN/Ag film/SiN/Ag grating.
- Transmittance simulated and fitted by two-port two-mode CMT with different *a* (nm)

- Theory

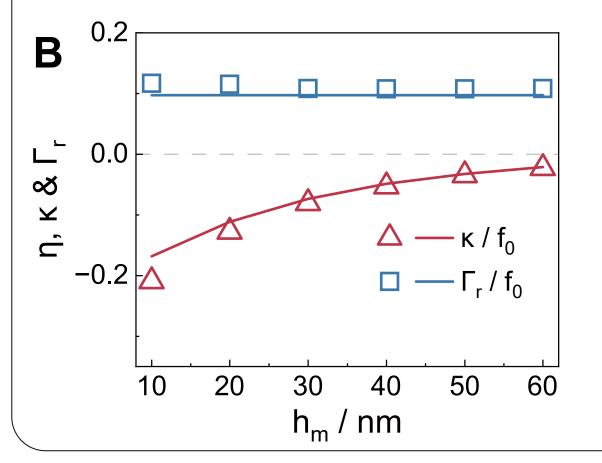
- Two SiN_x cavities support two F-P electromagnetic modes.
- Max transmittance is mainly controlled by Radiation Loss Γ_r and Nearfield Coupling κ , with optimal condition $\kappa = \Gamma_r$.

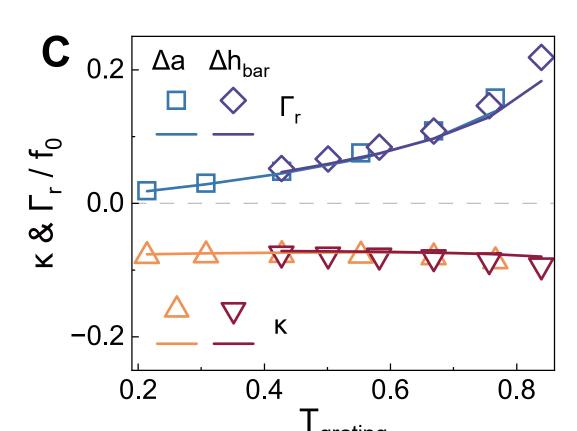


- A: κ and Γ_r are controlled by the geometry.
- • $h_{\rm m} \to K$; a, $h_{\rm bar} \to T_{\rm grating} \to \Gamma_r$.
- **B, C:** κ , Γ_r from theory (line, by Tight Binding Method and energy flow analysis) and simulation (scatter) agree well.



 $|\Gamma_r| > |\kappa|$

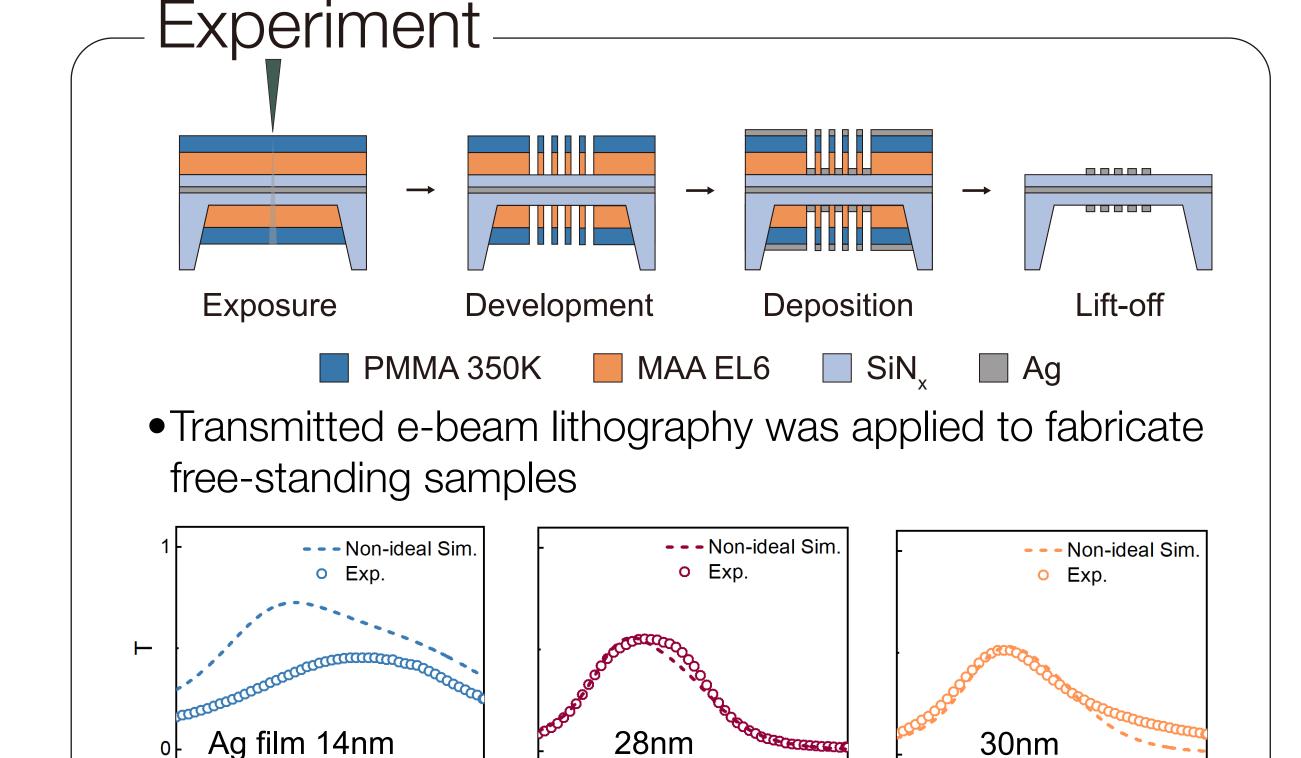




700

λ/nm

800



• Figure of Merit (FoM) ≈ 397 for our 28nm sample, comparable to ITO (FoM ≈ 350)

700

λ/nm

800

600

References

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